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OGOSH49USA

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re t	he Application of:)
) Examiner:
	Yuichiro Shindo et al.)
) Group Art Unit:
Appli	cation No.:)
)
Corresponding International Filing No.:)
	PCT/JP2004/013031)
)
Filed:	Herewith)
-	HIGH BURIEV CDIC OVER)
For:	HIGH PURITY ZINC OXIDE)
	POWDER AND METHOD FOR)
	PRODUCTION THEREOF, AND)
	HIGH PURITY ZINC OXIDE)
	TARGET AND THIN FILM OF)
	HIGH PURITY ZINC OXIDE)

Mail Stop PCT Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

SECOND PRELIMINARY AMENDMENT

Sir:

Please amend the above-identified patent application as follows.

Amendments to the Specification begin on page two of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page three of this paper.

Remarks begin on page seven of this paper.